EB POWER SUPPLY FOR FOCUSED ION BEAM



ISO9001:2015



- Standard ET interface, RS-232 control
 Electron Microscopy, Electron Beam, Ion Beam Power System
- High Accuracy, High Stability, Low Ripple
- Integrated Single Chassis Solution
- Corona Free Operation
- Overvoltage, overcurrent, short circuit and Acr protection

OEM customization available

INTRODUCTION

Wisman's EIB Series is an integrated multiple output high voltage power supply specifically designed for focused ion beam applications. An additional Lens Chassis is available, providing the high performance fixed or reversible polarity high voltage lenses required to focus the Ion Beam. Alloutputs are offered with ultra-low output ripple, excellent regulation, stability, temperature coefficient, drift and accuracy specifications. Isolation and control of the respective floating sources is provided via Wisman's proprietary high voltage isolation techniques. Customer control of this integrated EIB power supply system is accomplished via a fiber optic interface. All high voltage safety interlocks areof a failsafe hardware based design. Consult factory for final configuration requirements.

TYPICAL APPLICATION

Scanning electron microscopy, Semiconductor analysis,Electron beam; Ion beam,Life science,Medical Chemical, Science experiment, Industry Application, Ion beam etching,Focused ion-beam lithography,Vacuum gun, EIB SELECTION TABLE

Extractor Supply				Filament Supply				Suppressor Supply			
Voltage(kv)Current(uA)	Ripple	Stability	$Voltage\left(v\right)$	Current(A)	Ripple	Stability	Voltage(kv)	Current(uA)	Ripple	Stability
-15	400	<100mVp-p	500mv/10 hrs, after 2 hours' warm-up	5	5	10mAp-p	5mA/10min	±2	30	小于150mVp-p	500mv/10 hrs, after 2 hours' warm-up
16	1000	<160mVp-p	1. 6v/10 hrs, after 2 hours' warm-up	3.3	3	10mAp-p	5mA/10min	-1	150	小于20mVp-p	100mv/10 hrs, after 2 hours' warm-up

Accelerator Supply				LensA Supply				LensB Supply			
/oltage(kv	Current(uA)	Ripple	Stability	Voltage(kv	Current(uA)	Ripple	Stability	Voltage(kv)	Current(uA)	Ripple	Stability
45	30	<200mVp-p	1.5v/10 hrs, after 2 hours' warm-up	-40	30	150mVp-p	1v/10 hrs, after 2 hours' warm-up	25	30	<150mVp-p	1v/10 hrs, after 2 hours' warm-up
35	30	<200mVp-p	1.5v/10 hrs, after 2 hours' warm-up	30	30	100mVp-p	1v/10 hrs, after 2 hours' warm-up	30	30	<200mVp-p	1v/10 hrs, after 2 hours' warm-up
-60	150	<600mVp-p	6v/10 hrs, after 2 hours' warm-up		Long	(ontional)		ens(ont	ional)	1	

Lens	(optional)		Lens(optional)			
LensA	LensB		LensA	LensB		
+30kV	+25kV/-15kV		+/-30kV	+/-30kV		
-30kV	+25kV/-15kV		+/-20kV	+/-30kV		

EIB SELECTION EXAMPLE



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SPECIFICTION ISO9001:2015

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	PARAMETER	DESCRIPTION						
	Input	105Vac~240Vac,47~63Hz; +24Vac,±5%@5.5A.						
~	Output	Output Voltage 0~+45kv,output Current0~30uA,Referenced to Ground						
Accelerator	Load Regulation	\pm 0.001% (no load to rated load)						
	Line Regulation	$<$ 100mA(Input Voltage change \pm 10%)						
	Ripple	PIs turn to EIB selection table						
	Temperature coefficient	25ppm/℃						
	Stability	1.5v/10 hrs after 2 hrs' warm-up						
т	Output	Output Voltage0~+5vdc,output Current 0~5A,Referenced to Accelerator Supply						
	Load Regulation	\pm 0.1%(no load to rated load)						
iiia	Line Regulation	5mA(Input Voltage change \pm 10%)						
me	Temperature coefficient	<200ppm/℃						
nt	Ripple	PIs turn to EIB selection table						
	Stability	5mA/10mins after 2 hrs' warm-up						
S	Output	Output Voltage-2kV~+2kVdc,output Current 0~30uA,Referenced to Accelerator Supply						
dn	Load Regulation	\pm 0.01%(no load to rated load)						
pr	Line Regulation	100mA(Input Voltage change \pm 10%)						
e s	Temperature coefficient	25ppm/℃ 。						
SO	Ripple	PIs turn to EIB selection table						
	Stability	500mV/10hrs after 2 hours' warm-up						
-	Output	Output Voltage0V~-15kV,Output current 0~400uA,Referenced to Accelerator Voltage.						
X	Load regulation	\pm 0. 01%(no load to rated load)						
rac	Line regulation	100mV (Input voltage change±10%)						
to	Ripple	PIs turn to EIB selection table						
	Temperature coefficient	25ppm/°C						
	Stability	500mV/10hrs after 2 hours' warm-up						
_	Output	Output Voltage0~-40KVdc,Output current 0~30uA,Referenced to Ground						
er -	Load regulation	\pm 0. 01%(no load to rated load)						
ls/	Line regulation	100mV(Input Voltage change ±10%)						
	Ripple	Pls turn to EIB selection table						
	Temperature coefficient	25ppm/℃						
	Stability	1V/10 hrs after 2 hours's warm-up						
	Output	Output Voltage0v~+25KV,Output current 0~30uA,Referenced to Ground						
	Load regulation	±0.005% (no Load to rated load)						
en	Line regulation	00mV(Input Voltage change±10%)						
S E	Ripple	Pls turn to EIB selection table						
	Temperature coefficient	25ppm/℃。						
	Stability	1V/10 hrs after 2 hours' warm-up						
Storage temperature		-30°C~+70°C ₀						
Cooling		Natural convection						
Humility		10%~90%RH,no condensing						
Weight		20kg						





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- APPLICATION SPECIFIC

RS-232 DIGITAL INTERFACE

J3	SIGNAL	J3	SIGNAL
1	N/C	6	N/C
2	TXD/Transmit	7	N/C
3	RXD/Receive	8	N/C
4	N/C	9	N/C
5	GND		

ETHERNET DIGITAL INTERFACE

J5	SIGNAL	J5	SIGNAL
1	RX+ (Receive+)	6	TX-(Transmit-)
2	RX-(Receive-)	7	N/C
3	TX+(Transmit+)	8	N/C
4	N/C	9	N/C
5	GND		

EIB DIMENSION



Unit:inch(mm)





BACK VIEW



